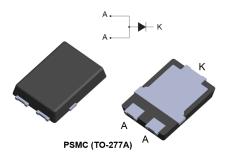


## STPST8H100

Datasheet

## 100 V - 8 A power Schottky trench rectifier





### Features

- ST trench patented process
- High junction temperature capability
- Low forward voltage drop
- Low recovery charges
- Reduces conduction, reverse and switching losses
- Avalanche tested
- Flat packages
- ECOPACK2 compliant

### **Applications**

- DC/DC converter
- LED lighting
- Flyback topology
- Auxiliary power supply
- Switch mode power supply (SMPS)

### **Description**

This 8 A, 100 V rectifier is based on ST trench technology that achieves the best-inclass  $V_{\rm F}/I_{\rm R}$  trade-off for a given silicon surface.

Integrated in flat and space-saving packages, this STPST8H100 trench rectifier is intended to be used in high frequency miniature switched mode power supplies. It is also an ideal candidate for auxiliary power supply in telecom, server, or smart metering. ST trench rectifiers are adapted to freewheeling, OR-ring or reverse polarity protection applications, and can be the perfect companion device to our transistors, drivers, or ST VIPer products.



### Product status link STPST8H100

Product summary			
I <sub>F(AV)</sub>	8 A		
V <sub>RRM</sub>	100 V		
T <sub>j</sub> (max.)	175 °C		
V <sub>F</sub> (typ.)	0.560 V		



### 1 Characteristics

# Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified, with 2 anode terminals short-circuited)

Symbol	Paramet	Value	Unit		
V <sub>RRM</sub>	Repetitive peak reverse voltage			100	V
I <sub>F(AV)</sub>	Average forward current, $\delta$ = 0.5, square wave $T_c$ = 155 °C			8	А
I <sub>FSM</sub>	Surge non repetitive forward current t <sub>p</sub> = 10 ms sinusoidal			200	А
I <sub>AS</sub>	Single pulse avalanche current <sup>(1)</sup> $T_j = 25^{\circ}C, L = 300 \mu$ H, V <sub>DD</sub> = 15 V			12	А
T <sub>stg</sub>	Storage temperature range			-65 to +175	°C
Тј	Maximum operating junction temperature <sup>(2)</sup>			+175	°C

1. Please refer to Figure 1 and Figure 2 for the unclamped inductive switching test circuit, and waveform.

2.  $(dP_{tot}/dT_i) < (1/R_{th(i-a)})$  condition to avoid thermal runaway for a diode on its own heatsink.

#### Table 2. Thermal resistance parameter

Symbol	Parameter	Typ. value	Unit
R <sub>th(j-c)</sub>	Junction to case	1.4	°C/W

For more information, please refer to the following application note:

AN5088: Rectifiers thermal management, handling and mounting recommendations

#### Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
		T <sub>j</sub> = 125 °C	V <sub>R</sub> = 70 V	-	1.5	4.6	mA
I <sub>R</sub> <sup>(1)</sup>	Reverse leakage current	T <sub>j</sub> = 25 °C	V <sub>R</sub> = 100 V	-		17	μA
		T <sub>j</sub> = 125 °C		-	3	10	mA
		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 4 A	-	0.530	0.590	V
V <sub>F</sub> <sup>(2)</sup>	Forward voltage drop	T <sub>j</sub> = 125 °C		-	0.460	0.515	
		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 8 A	-	0.625	0.695	
		T <sub>j</sub> = 125 °C		-	0.560	0.615	

1. Pulse test:  $t_p = 5 ms$ ,  $\delta < 2\%$ 

2. Pulse test:  $t_p = 380 \ \mu s, \ \delta < 2\%$ 

To evaluate the conduction losses, use the following equation:

 $P = 0.415 \text{ x } I_{F(AV)} + 0.025 \text{ x } I_{F}^{2}(RMS)$ 

For more information, please refer to the following application notes related to the power losses :

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode





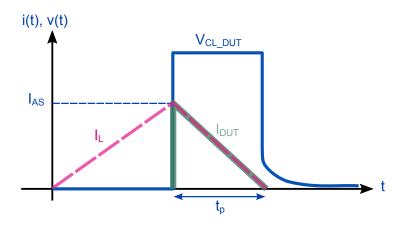
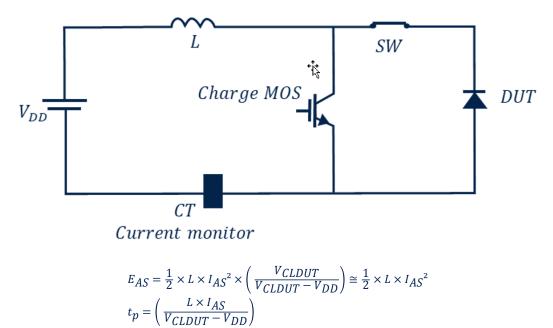
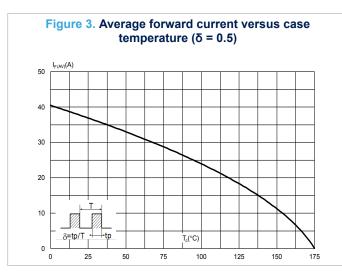


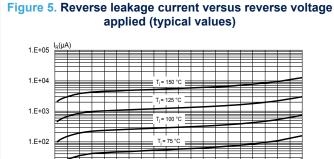
Figure 2. Unclamped Inductive Switching Test circuit





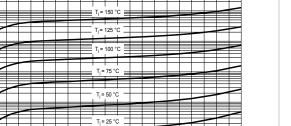
#### **Characteristics (curves)** 1.1





30 40 50 60 70 80 90 100

20



 $V_R(V)$ 

V<sub>F</sub>(V)

0.8

0.9

0.7

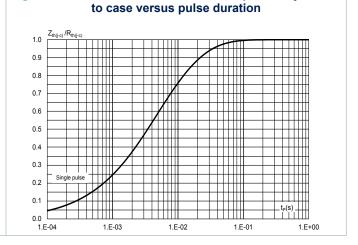
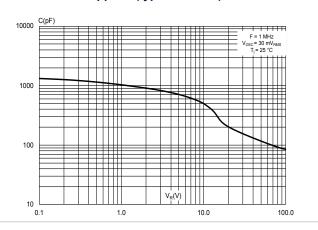
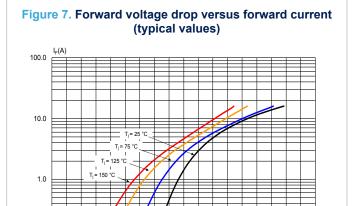
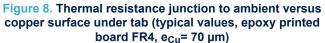


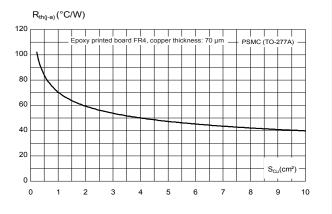
Figure 4. Relative variation of thermal impedance junction

Figure 6. Junction capacitance versus reverse voltage applied (typical values)









0.1 0.0

0.1

0.2

0.3

0.4

0.5

0.6

1.E+01

1.E+00

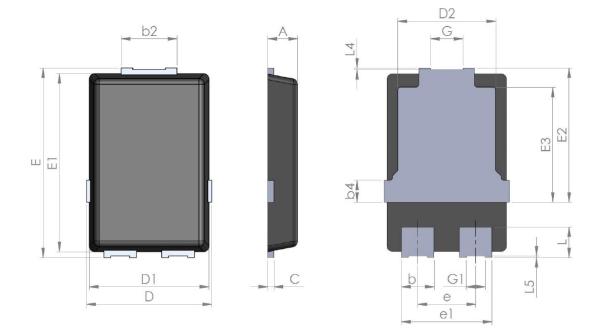
1.E-01

### 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

### 2.1 PSMC (TO-277A) package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)



### Figure 9. PSMC (TO-277A) package outline

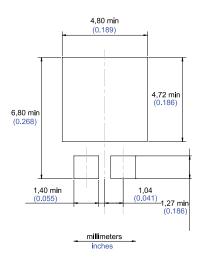
*Note:* This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.



	Dimensions							
Ref.		Millimeters			Inches (for reference only)			
	Min.	Тур.	Max.	Min.	Тур.	Max.		
А	1.00	1.10	1.20	0.039	0.043	0.047		
b	1.05	1.20	1.35	0.041	0.047	0.053		
b2	1.90	2.05	2.20	0.075	0.081	0.087		
b4		0.75			0.029			
С	0.15	0.23	0.40	0.006	0.009	0.016		
D	4.45	4.60	4.75	0.175	0.181	0.187		
D1	4.25	4.40	4.45	0.167	0.173	0.175		
D2	3.40	3.60	3.70	0.134	0.142	0.146		
E	6.35	6.50	6.65	0.250	0.256	0.262		
E1	6.05	6.10	6.15	0.238	0.240	0.242		
E2	4.50	4.60	4.70	0.177	0.181	0.185		
E3		3.94			1.55			
е		2.13			0.084			
e1		3.33			0.131			
G		1.20			0.047			
G1		0.70			0.027			
L	0.90	1.05	1.24	0.035	0.041	0.049		
L4	0.02			0.0008				
L5	0.02			0.0008				

### Table 4. PSMC (TO-277A) package mechanical data

### Figure 10. PSMC (TO-277A) package footprint in mm (in inches)



Note: For package and tape orientation, reel and inner box dimensions and tape outline please check TN1173.



## **3** Ordering information

Table 5. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPST8H100SF	T8H1	PSMC (TO-277A)	90.0 mg	6000	Tape and reel

### **Revision history**

### Table 6. Document revision history

Date	Revision	Changes
02-Jan-2023	1	Initial release.

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